

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- Enhanced power dissipation capability of 1200 mW

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V_{GS} = 10 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	7.6	A
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 6 A; T _j = 25 °C		-	17	21	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2. P	inning inf	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain		G-UF-4
				S
				017aaa253
			TO-236AB (SOT23)	

6. Ordering information

Table 3. Ordering informType number	Package							
	Name	Description	Version					
PMV20EN	TO-236AB	plastic surface-mounted package; 3 leads	SOT23					

7. Marking

Table 4.	Marking	codes
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Type number	Marking code[1]
PMV20EN	%КС

[1] % = placeholder for manufacturing site code

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8. Limiting values

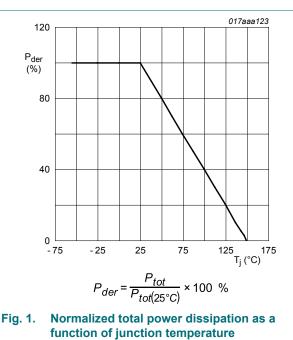
Table 5. Limiting values

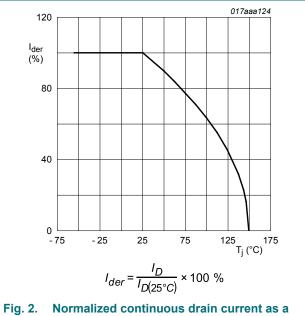
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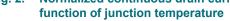
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage	_		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	7.6	А
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	6	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	3.8	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	24	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	510	mW
			[1]	-	1200	mW
		T _{sp} = 25 °C		-	6940	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode		·			
I _S	source current	T _{amb} = 25 °C	[1]	-	1.1	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.







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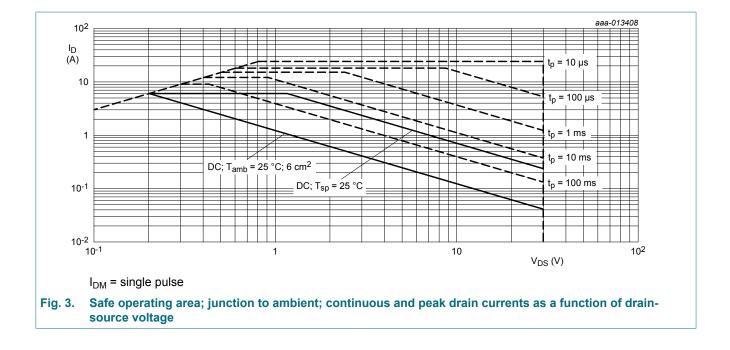
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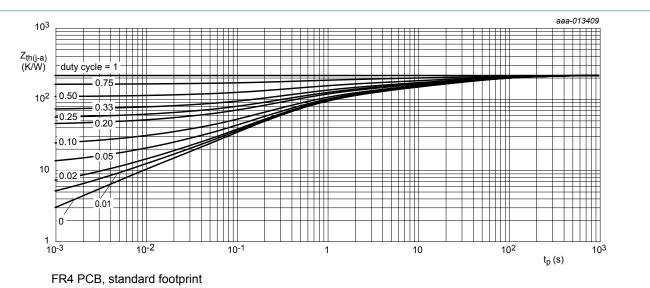
9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1]	-	208	245	K/W
	from junction to ambient		[2]	-	88	104	K/W
		in free air; t ≤ 5 s	[2]	-	55	65	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	13	18	K/W

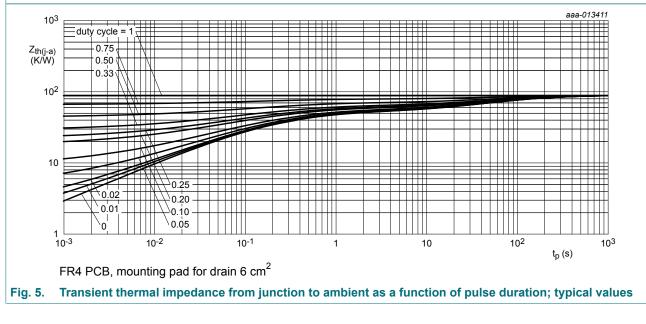
Table 6 Thermal characteristics

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².





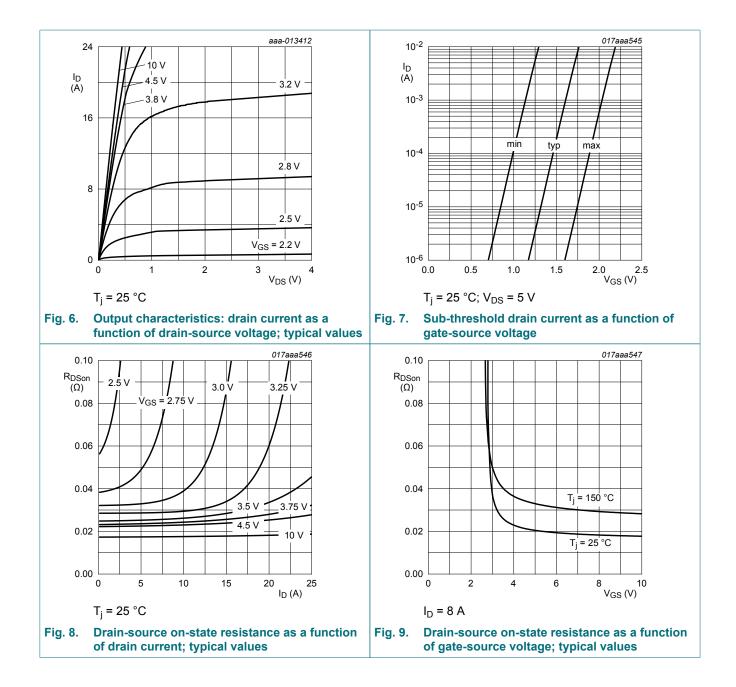


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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	icteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	30	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	1	1.5	2	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 6 A; T _j = 25 °C	-	17	21	mΩ
	resistance	V _{GS} = 10 V; I _D = 6 A; T _j = 150 °C	-	27	34	mΩ
		V_{GS} = 4.5 V; I _D = 5.4 A; T _j = 25 °C	-	21	26	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 2 A; T _j = 25 °C	-	13	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	1.7	-	Ω
Dynamic ch	aracteristics	· · · ·				·
Q _{G(tot)}	total gate charge	$V_{DS} = 15 \text{ V}; \text{ I}_{D} = 5 \text{ A}; \text{ V}_{GS} = 10 \text{ V};$	-	7.2	10.8	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1	-	nC
Q _{GD}	gate-drain charge		-	0.7	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	435	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	90	-	pF
C _{rss}	reverse transfer capacitance		-	35	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 15 V; I _D = 5 A; V _{GS} = 10 V;	-	9	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	17	-	ns
t _{d(off)}	turn-off delay time]	-	9	-	ns
t _f	fall time		-	8	-	ns
Source-drai	n diode					
V _{SD}	source-drain voltage	I _S = 1.1 A; V _{GS} = 0 V; T _i = 25 °C	-	0.75	1.2	V

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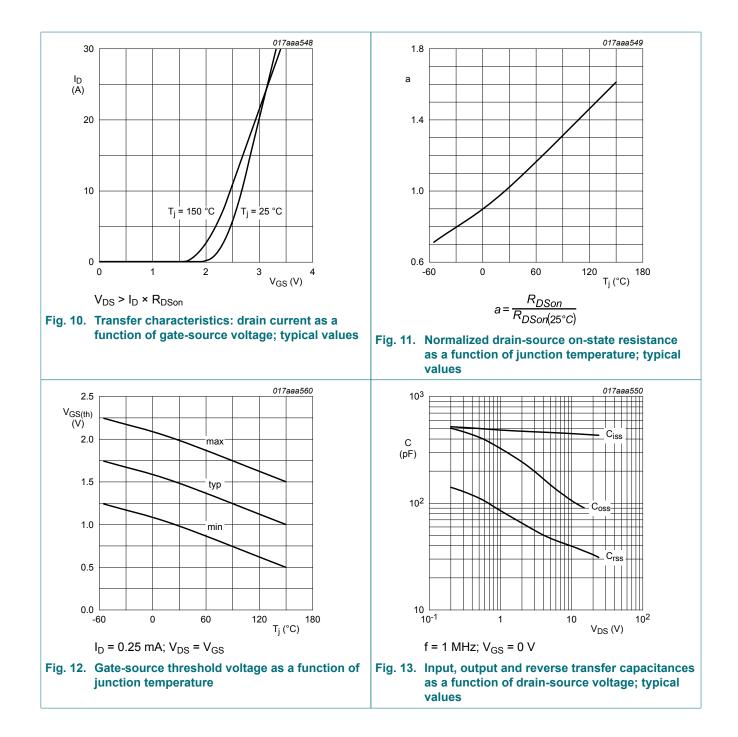


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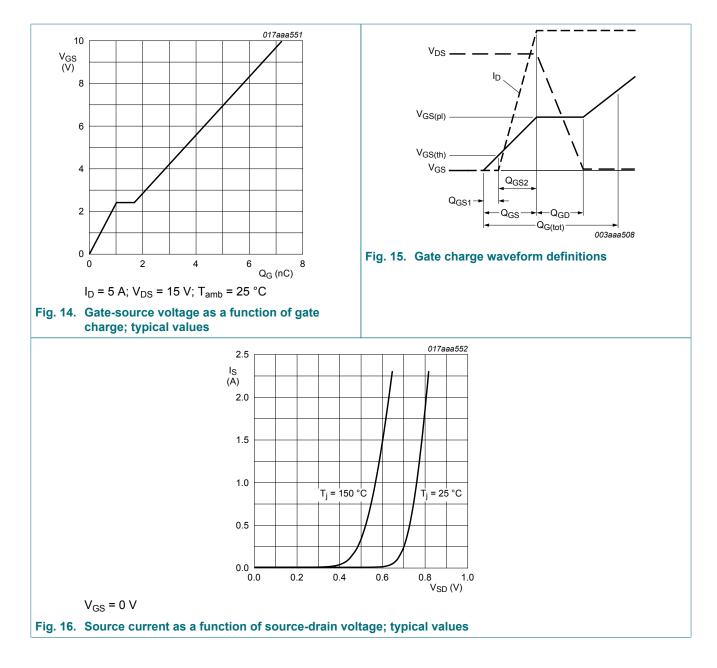
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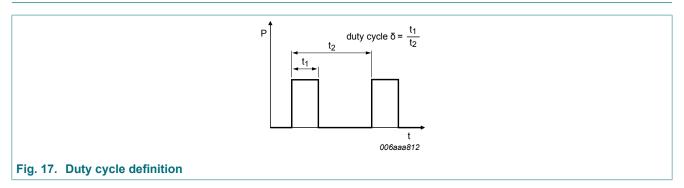
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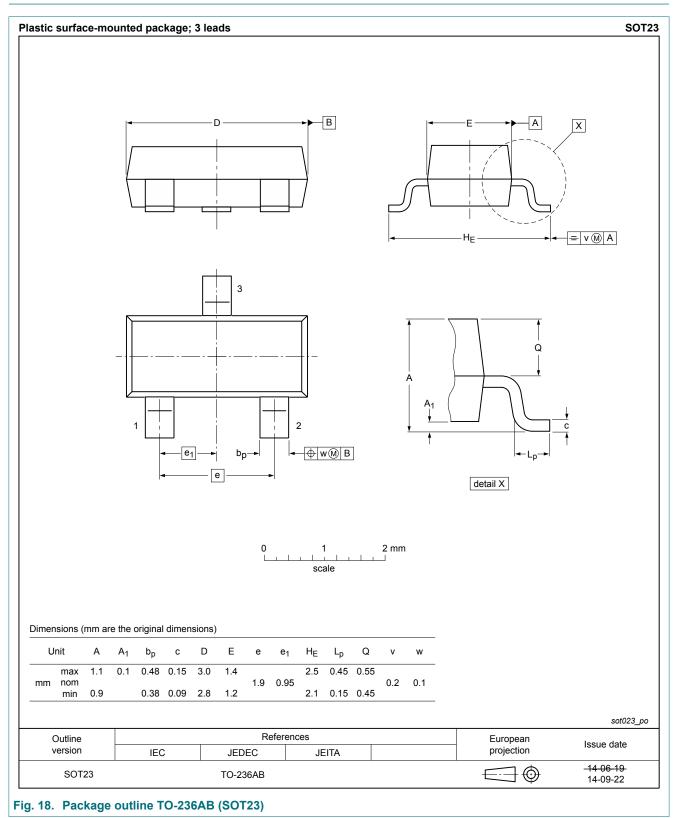
11. Test information



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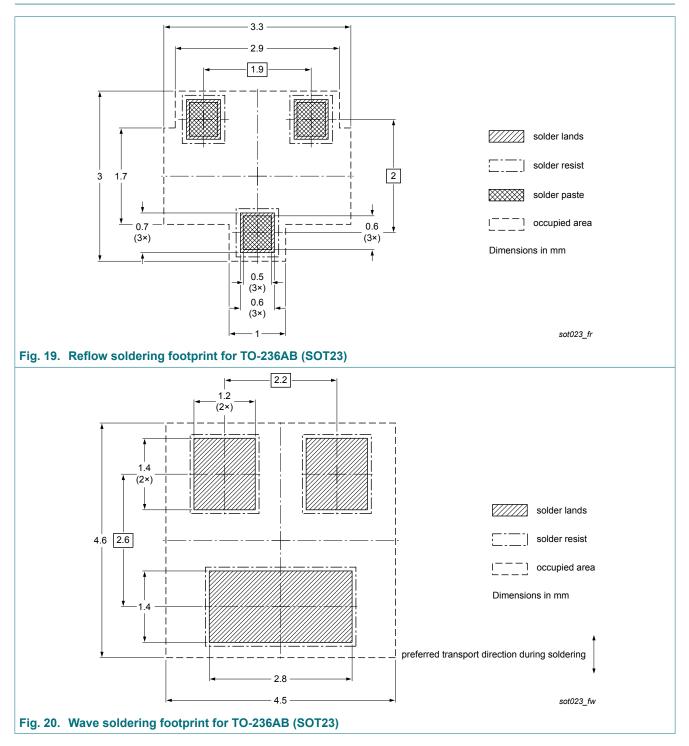
12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMV20EN v.2	20180705	Product data sheet	-	PMV20EN v.1		
Modifications:	Adaption of the	Adaption of the typical value of g _{fs} according to new wafer fab				
PMV20EN v.1	20140605	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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